NSN 5961-01-028-0010

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-028-0010 **Inclosure Material:** Plastic **Overall Length:** Between 0.980 inches and 1.100 inches **Overall Diameter:** Between 0.970 inches and 1.000 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud Thready Qty Per Inch (tpi): 32 **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 15000.0 reverse voltage, peak **Current Rating Per Characteristic:** 0.25 amperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Stackable design **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded hole and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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